

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	23	nanocrystalline with polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/17 23:30
S2	415	nanocrystalline with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/17 23:31
S3	15	nanocrystalline with silicon and substrate with ("690" or "700")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/17 23:34
S4	96	nanocrystalline with silicon and substrate with heat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/17 23:35
S5	16	nanocrystalline with silicon and substrate with heat\$3 and lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:47
S6	6	nanocrystalline with silicon and substrate with heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:47
S7	161	nano\$9 with silicon and substrate with heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:38
S8	0	nanopolysilicon and substrate with heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:49

EAST Search History

S9	0	nanopolysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:49
S10	20	nanosilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:53
S11	0	S10 and substrate with heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:49
S12	0	S10 heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:49
S13	0	S10 heat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 13:49
S14	54	"5754477"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:08
S15	182	nano-crystal with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:37
S16	49	nano-crystal with silicon and heat\$3 same substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:09

EAST Search History

S17	0	nano-crystal with silicon and heat\$3 same substrate same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:09
S18	49	nano-crystal with silicon and heat\$3 same substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:09
S19	6	nano-crystal with silicon same heat\$3 same substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:36
S20	0	nano-crystal with silicon same heat\$3 same substrate same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 14:36
S21	37	nano\$9 near silicon and substrate with heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 15:26
S22	0	nanograin near silicon and substrate with heat\$3 same lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 15:00
S23	0	nano-grain near silicon and substrate with heat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 15:00
S24	3	nano-grain with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 15:02

EAST Search History

S25	10	nano-grain same silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/18 15:02
S26	125	(438/764).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/18 15:26
S27	2522	substrate with heat\$3 and nano\$9 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:46
S28	18052	substrate with heat\$3 and nano\$9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:46
S29	900	substrate with heat\$3 same lamp and nano\$9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:46
S31	161	substrate with heat\$3 same lamp and nano\$9 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:46
S32	68	substrate near heat\$3 same lamp and nano\$9 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:47
S33	41	substrate near heat\$3 with lamp and nano\$9 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:48

EAST Search History

S34	3	substrate near heat\$3 with lamp and nanocrystal\$4 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:50
S35	6	substrate with heat\$3 with lamp and nanocrystal\$4 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:56
S36	0	substrate with heat\$3 with lamp and nano-crystal\$4 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:57
S37	0	substrate with heat\$3 same lamp and nano-crystal\$4 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 22:57
S38	9	substrate with heat\$3 same lamp and nanocrystal\$4 with silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:05
S39	29	substrate with heat\$3 with lamp and nanocrystal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:09
S40	0	"CHAKRAVARTI-ASHIMA.in. "	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:09
S41	0	"CHAKRAVARTI-ASHIMA.in. "	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:10

EAST Search History

S42	21	CHAKRAVARTI-ASHIMA-B.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:35
S43	0	power with lamp with workpiece same polysilicon deposition	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:36
S44	0	power with lamp with substrate same polysilicon deposition	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:36
S45	1	power with lamp with substrate same polysilicon with deposition	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:37
S46	3	power with lamp with substrate same polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:39
S47	0	lamp with backside with substrate same polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:40
S48	0	lamp with lower surface with substrate same polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:40
S49	121	lamp with substrate same polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:41

EAST Search History

S50	993	(438/795).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/19 23:42
S51	227	(438/799).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/19 23:42
S52	299	S50 and lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:42
S53	90	S50 and lamp and polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 00:29
S54	0	S50 and lamp and polysilicon and nanocrystal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:45
S55	0	S50 and lamp and nanocrystal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:45
S56	1	S50 and nanocrystal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/19 23:45
S57	95	lamp with below with substrate and polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 00:55

EAST Search History

S58	22	lamp with below with substrate and polysilicon with cvd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 00:59
S59	30	lamp with below with substrate and polysilicon same cvd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:01
S60	1	lamp with below with substrate and nanograin	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:02
S61	77	nanograin	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:07
S62	33	nanograin and silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:08
S63	1962	nanocrystal and silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:08
S64	77	nanocrystal and silicon and cvd and lamp	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:14
S65	1120	(438/488).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/20 01:14

EAST Search History

S66	71	(438/495).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/20 01:14
S67	993	(438/795).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/20 01:14
S68	0	S64 and S67	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:16
S69	64	S64 and cvd and lamp and power	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/03/20 01:16